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# 74VCX16838

Connection D	agram	
00 - 00 - 00 - 00 - 00 - 00 - 00 - 00	1 48 2 47 3 46 4 45 5 44 6 43 7 42 8 41	- CP - Io - Ih - GND - I2 - I3 - V <sub>CC</sub> - I4
$\begin{array}{c} \mathbf{o}_{5} & - \\ \mathbf{GND} & - \\ \mathbf{O}_{6} & - \\ \mathbf{o}_{7} & - \\ \mathbf{o}_{8} & - \\ \mathbf{o}_{9} & - \\ \mathbf{O}_{9} & - \\ \mathbf{GND} & - \\ \mathbf{O}_{10} & - \\ \mathbf{O}_{10} & - \end{array}$	9 40 10 39 11 38 12 37 13 36 14 35 15 34 16 33	- I5 - GND - I6 - I7 - I8 - I9 - OND - I
910 9,1 Vcc 012 0,3  0,4 0,4 NC	17 32   18 31   19 30   20 29   21 28   22 27   23 26   24 25	- ho - h1 - Vcc - h2 - h3 - GND - h4 - h5 - REGE

# **Truth Table**

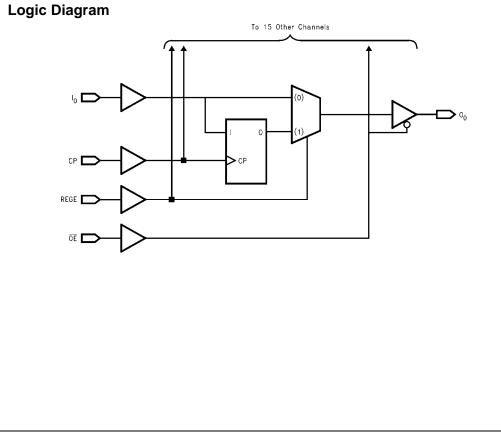
	Outputs			
СР	REGE	I <sub>n</sub>	OE	On
$\uparrow$	Н	Н	L	н
$\uparrow$	н	L	L	L
х	L	н	L	н
х	L	L	L	L
х	Х	х	н	Z

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float) Z = High Impedance

### **Functional Description**

The 74VCX16838 consists of sixteen selectable noninverting buffers or registers with word wide controls. Mode functionality is selected through operation of the CP and REGE pin as shown by the truth table. When REGE is held at a logic "1" the device operates as a 16-bit register. Data is transferred from  ${\rm I_n}$  to  ${\rm O_n}$  on the rising edge of the CP pin. When the REGE pin is held at a logic "0" the device operates in a flow through mode and data propagates directly from the I to the O outputs. All outputs can be 3-STATE by holding the  $\overline{OE}$  pin at a logic "1."



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# Absolute Maximum Ratings(Note 2)

# Recommended Operating

Supply Voltage (V <sub>CC</sub> )	-0.5V to +4.6V
DC Input Voltage (VI)	-0.5V to +4.6V
Output Voltage (V <sub>O</sub> )	
Outputs 3-STATE	-0.5V to +4.6V
Outputs Active (Note 3)	–0.5V to $V_{CC}$ +0.5V
DC Input Diode Current (I <sub>IK</sub> ) $V_I < 0V$	–50 mA
DC Output Diode Current (I <sub>OK</sub> )	
V <sub>O</sub> < 0V	–50 mA
$V_{O} > V_{CC}$	+50 mA
DC Output Source/Sink Current	
(I <sub>OH</sub> /I <sub>OL</sub> )	±50 mA
DC V <sub>CC</sub> or GND Current per	
Supply Pin (I <sub>CC</sub> or GND)	±100 mA
Storage Temperature Range (T <sub>STG</sub> )	$-65^{\circ}C$ to $+150^{\circ}C$

Conditions (Note 4)	5
Power Supply	
Operating	1.65V to 3.6V
Data Retention Only	1.2V to 3.6V
Input Voltage	-0.3V to +3.6V
Output Voltage (V <sub>O</sub> )	
Output in Active States	0V to V <sub>CC</sub>
Output in "OFF" State	0.0V to 3.6V
Output Current in I <sub>OH</sub> /I <sub>OL</sub>	
$V_{CC} = 3.0V$ to 3.6V	±24 mA
$V_{CC} = 2.3V$ to 2.7V	±18 mA
V <sub>CC</sub> = 1.65V to 2.3V	±6 mA
Free Air Operating Temperature (T <sub>A</sub> )	$-40^{\circ}C$ to $+85^{\circ}C$
Minimum Input Edge Rate ( $\Delta t / \Delta V$ )	
$V_{\text{IN}}$ = 0.8V to 2.0V, $V_{\text{CC}}$ = 3.0V	10 ns/V

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Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3:  $\mathrm{I}_{\mathrm{O}}$  Absolute Maximum Rating must be observed.

Note 4: Floating or unused inputs must be held HIGH or LOW.

# DC Electrical Characteristics (2.7V $< V_{CC} \leq 3.6V)$

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.7–3.6	2.0		V
V <sub>IL</sub>	LOW Level Input Voltage		2.7–3.6		0.8	V
V <sub>OH</sub>	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	2.7–3.6	V <sub>CC</sub> - 0.2		V
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I <sub>OH</sub> = -18 mA	3.0	2.4		V
		I <sub>OH</sub> = -24 mA	3.0	2.2		V
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.7–3.6		0.2	V
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
		I <sub>OL</sub> = 18 mA	3.0		0.4	V
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	V
I <sub>I</sub>	Input Leakage Current	$0 \le V_I \le 3.6V$	2.7–3.6		±5.0	μΑ
oz	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or $V_{IL}$	2.7–3.6		±10	μA
OFF	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μΑ
сс	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.7–3.6		20	μΑ
		$V_{CC} \leq (V_I, V_O) \leq 3.6V \text{ (Note 5)}$	2.7–3.6		±20	μΑ
۵l <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6	1	750	μΑ

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Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
/н	HIGH Level Input Voltage		2.3–2.7	1.6		V
/IL	LOW Level Input Voltage		2.3–2.7		0.7	V
/ <sub>ОН</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.3–2.7	V <sub>CC</sub> - 0.2		V
		I <sub>OH</sub> = -6 mA	2.3 2.3	2.0		V
		$I_{OH} = -12 \text{ mA}$		1.8		V
		I <sub>OH</sub> = -18 mA	2.3	1.7		V
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3–2.7		0.2	V
		I <sub>OL</sub> = 12 mA	2.3		0.4	V
		I <sub>OL</sub> = 18 mA	2.3		0.6	V
1	Input Leakage Current	$0 \le V_I \le 3.6V$	2.3–2.7		±5.0	μΑ
oz	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	2.3-2.7		±10	
		$V_I = V_{IH} \text{ or } V_{IL}$	2.3-2.1		±10	μA
OFF	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10	μA
сс	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–2.7		20	μΑ
		$V_{CC} \le (V_I, V_O) \le 3.6V$ (Note 6)	2.3-2.7	1	±20	μΑ

Note 6: Outputs disabled or 3-STATE only.

# DC Electrical Characteristics (1.65V $\leq$ V\_{CC} < 2.3V)

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
VIH	HIGH Level Input Voltage		1.65 - 2.3	$0.65 \times V_{CC}$		V
V <sub>IL</sub>	LOW Level Input Voltage		1.65 - 2.3		$0.35 \times V_{CC}$	V
V <sub>OH</sub>	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	1.65 - 2.3	V <sub>CC</sub> - 0.2		V
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		V
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	1.65 - 2.3		0.2	V
		I <sub>OL</sub> = 6 mA	1.65		0.3	V
l <sub>l</sub>	Input Leakage Current	$0 \le V_I \le 3.6V$	1.65 - 2.3		±5.0	μA
I <sub>OZ</sub>	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.65 - 2.3		±10	μA
		$V_I = V_{IH} \text{ or } V_{IL}$	1.05 - 2.5		10	μΑ
I <sub>OFF</sub>	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μΑ
		$V_{CC} \leq (V_I, V_O) \leq 3.6V$ (Note 7)	1.65 - 2.3		±20	μΑ

Note 7: Outputs disabled or 3-STATE only.

AC Electrical C	Characteristics	(Note 8)
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		$T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $C_L = 30$ pF, $R_L = 500\Omega$						
Symbol	Parameter	$V_{CC}=\textbf{3.3V}\pm\textbf{0.3V}$		$\textbf{V}_{\textbf{CC}} = \textbf{2.5V} \pm \textbf{0.2V}$		$V_{CC}=1.8V\pm0.15V$		Units
		Min	Мах	Min	Max	Min	Max	
f <sub>MAX</sub>	Maximum Clock Frequency	250		200		100		MHz
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay I <sub>n</sub> to O <sub>n</sub> (REGE = 0)	0.8	2.5	1.0	3.5	1.5	7.0	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay CP to O <sub>n</sub> (REGE = 1)	0.8	3.0	1.0	4.0	1.5	8.0	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay REGE to On	0.8	3.0	1.0	4.0	1.5	8.0	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time	0.8	3.5	1.0	4.7	1.5	9.4	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time	0.8	3.5	1.0	3.9	1.5	7.0	ns
t <sub>S</sub>	Setup Time	1.0		1.0		2.5		ns
t <sub>H</sub>	Hold Time	0.7		0.7		1.0		ns
t <sub>W</sub>	Pulse Width	1.5		1.5		4.0		ns
t <sub>OSHL</sub>	Output to Output Skew (Note 9)		0.5		0.5		0.75	ns

Note 8: For  $C_L = 50_PF$ , add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ).

# Extended AC Electrical Characteristics (Note 10)

		T <sub>A</sub> = −0°C to +8	85°C, $R_L = 500\Omega V_{CC} = 3.3V \pm 0.3V$	
		C <sub>L</sub> = 50 pF		
Symbol Parameter	Parameter	Min	Max	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay $I_n$ to $O_n$ (REGE = 0)	1.0	2.8	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay CP to $O_n$ (REGE = 1)	1.4	3.3	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Prop Delay REGE to On	1.0	3.3	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time	1.0	3.8	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time	1.0	3.8	ns
t <sub>S</sub>	Setup Time	1.0		ns
t <sub>H</sub>	Hold Time	0.7		ns

Note 10: This parameter is guaranteed by characterization but not tested.

# **Dynamic Switching Characteristics**

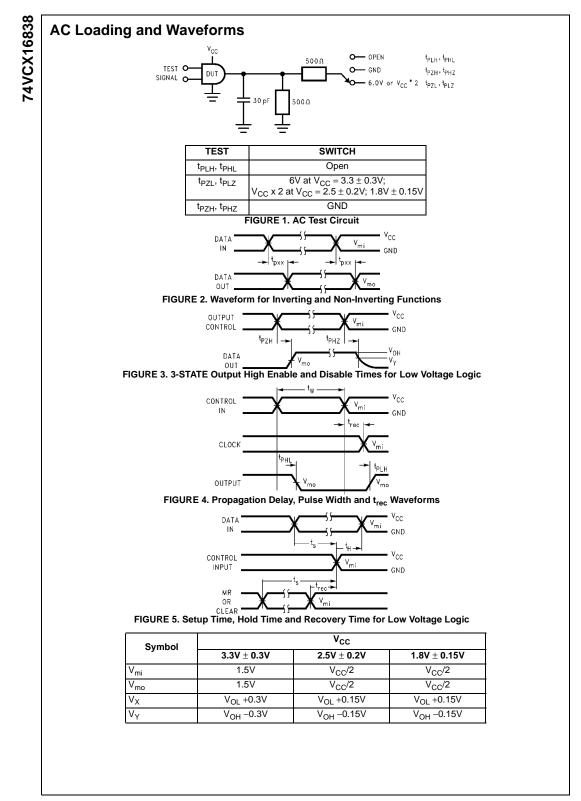
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C	Units
			(•)	Typical	
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 30 \text{ pF}, \text{ V}_{IH} = \text{V}_{CC}, \text{ V}_{IL} = 0 \text{V}$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_{L} = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V <sub>OHV</sub>	Quiet Output Dynamic Valley V <sub>OH</sub>	$C_{L} = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

# Capacitance

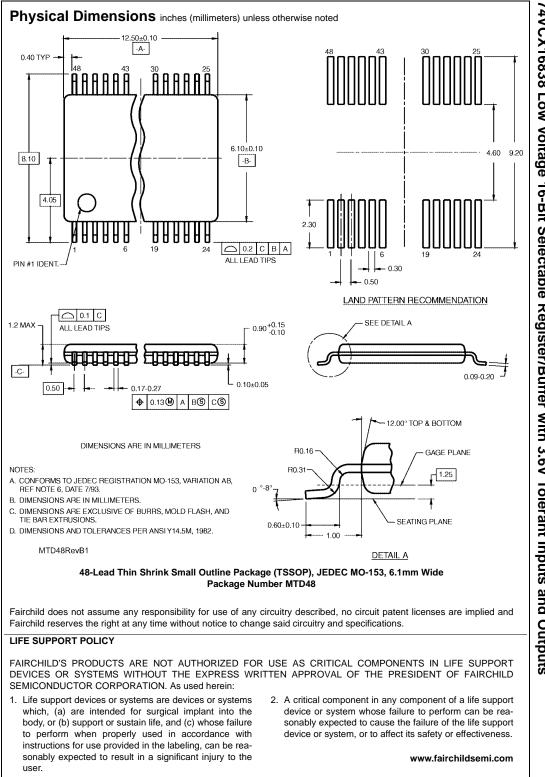
Symbol	Parameter	Conditions	T <sub>A</sub> = +25°C Typical	Units
CIN	Input Capacitance	$V_{CC}$ = 1.8V, 2.5V or 3.3V, $V_{I}$ = 0V or $V_{CC}$	6	pF
C <sub>OUT</sub>	Output Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{I} = 0V \text{ or } V_{CC}, f = 10 \text{ MHz},$ $V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20	pF

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